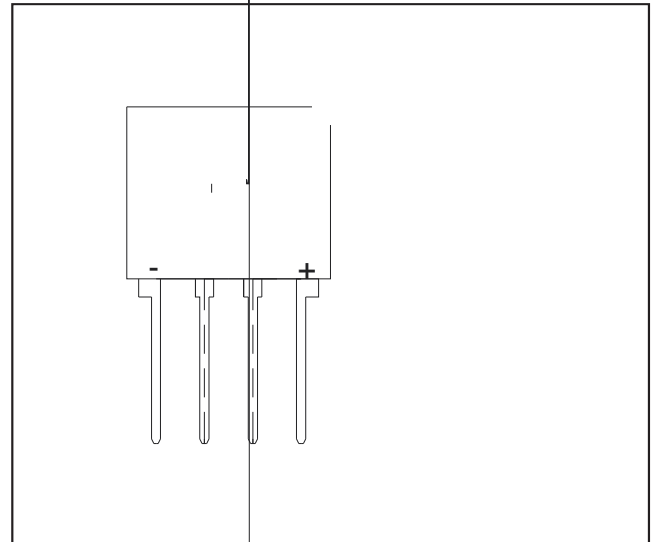
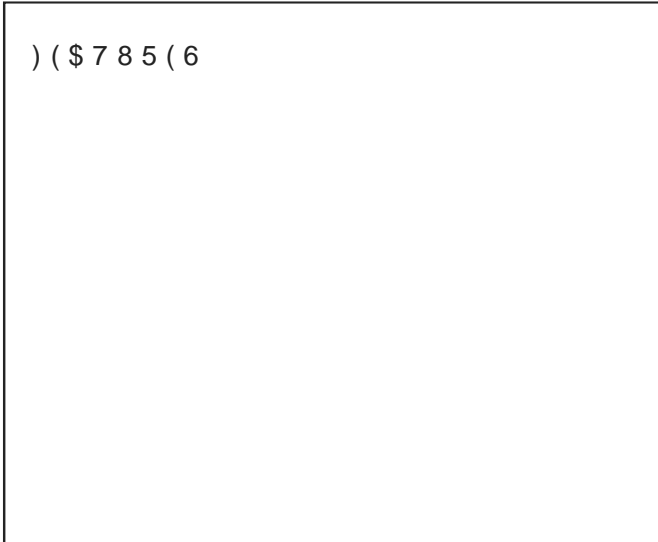


GBU SILICON BRIDGE RECTIFIER VOLTAGE:)\$ --- %\$00V CURRENT: .0A



		GBU 25A	GBU 25B	GBU 25D	GBU 25G	GBU 25J	GBU 25K	GBU 25M	UNITS
Maximum recurrent peak reverse voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V_{RMS}	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	V_{DC}	50	100	200	400	600	800	1000	V
Maximum average forward output current @ $T_c=100^\circ C$	$I_{F(AV)}$	25.0							A
Peak forward surge current 8.3ms single half-sine-wave superimposed on rated load	I_{FSM}	340							A
Maximum instantaneous forward voltage at 12.5 A	V_F	1.0							V
Maximum reverse current @ $T_A=25^\circ C$ at rated DC blocking voltage @ $T_A=125^\circ C$	I_R	5.0 500.0							A mA
Typical junction capacitance per leg (note 3)	C_J	211				94			pF
Typical thermal resistance per leg (note 2)	R_{JA}	21.0							°C/W
(note 1)	R_{JC}	2.2							
Operating junction temperature range	T_J	- 55 ---- + 150							°C
Storage temperature range	T_{STG}	- 55 ---- + 150							°C

NOTE: 1. Unit case mounted on 3.2x3.2x0.12" thick (6.2x8.2x0.3cm) Al. Plate.
 2. Units mounted in free air, no heat sink on P.C.B., 0.5x0.5"(12x12mm) copper pads, 0.375"(9.5mm) lead length.
 3. Measured at 1.0 MHz and applied reverse voltage of 4.0 volts.

